TOSHIBA Multichip Discrete Device

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HN7G06FU

- Power Management Switch Applications, Inverter Circuit Applications, Driver Circuit Applications and Interface Circuit Applications
- Combining transistor and BRT reduces the parts count, enabling the design of more compact equipment with a simpler system configuration.

Q1: 2SA1955F equivalent Q2: RN1104F equivalent

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-15	V
Collector-emitter voltage	V _{CEO}	-12	٧
Emitter-base voltage	V_{EBO}	-5	٧
Collector current	IC	-500	mA
Base current	Ι _Β	-50	mA

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	٧
Emitter-base voltage	V_{EBO}	10	٧
Collector current	Ic	100	mA

Q1, Q2 Common Ratings (Ta = 25°C)

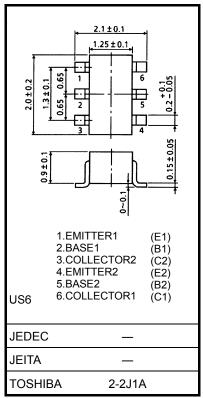
Characteristic	Symbol	Rating	Unit
Collector power dissipation	Pc*	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

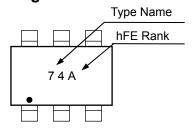
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



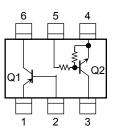


Weight: 0.0068 g (typ.)

Marking



Equivalent Circuit



^{*:} Total rating. 130 mW per element should not be exceeded.

Q1 Electrical Characteristics (Ta = 25°C)

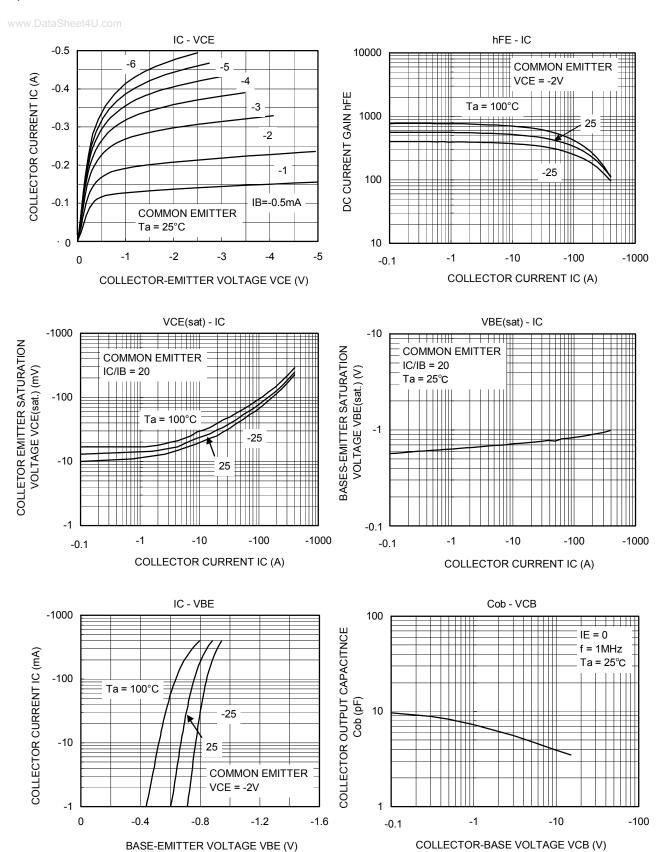
v.DataSheet4U com Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cutoff current		I _{CBO}	$V_{CB} = -15 \text{ V}, I_E = 0$	_	_	-100	nA
Emitter cutoff current		I _{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$	_	_	-100	nA
DC current gain	DC current gain		$V_{CE} = -2 \text{ V}, I_{C} = -10 \text{ mA}$	300	_	1000	
Collector-emitter saturation voltage		V _{CE} (sat)(1)	$I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$	_	-15	-30	mV
		V _{CE} (sat)(2)	$I_C = -200 \text{ mA}, I_B = -10 \text{ mA}$	_	-110	-250	
Base-emitter saturation voltage		V _{BE} (sat)	$I_C = -200 \text{ mA}, I_B = -10 \text{ mA}$	_	-0.87	-1.2	V
Transition frequency		f _T	$V_{CE} = -2 \text{ V}, I_{C} = -10 \text{ mA}$	_	130	_	MHz
Collector output capacitance		C _{ob}	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1 MHz	_	4.2	_	pF
-	Turn-on time	t _{on}	OUTPUT INPUT 300Ω OV OV OV OV OV OV OV OV OV O	_	40	_	ns
	Storage time	t _{stg}		_	280	_	ns
	Fall time	t _f			65	_	ns

**: h_{FE} Classification A:300~600, B:500~1000

Q2 Electrical Characteristics (Ta = 25°C)

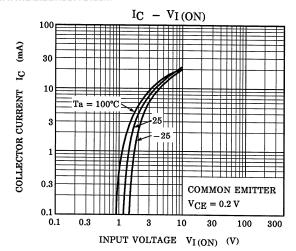
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cutoff current	I _{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$	_	_	100	nA
	I _{CEO}	V _{CE} = 50 V, I _E = 0	_	_	500	nA
Emitter cutoff current	I _{EBO}	V _{EB} = 10 V, I _C = 0	0.082	_	0.15	mA
DC current gain	h _{FE}	V _{CE} = 5 V, I _C = 10 mA	80	_	_	
Collector-emitter saturation voltage	V _{CE} (sat)	$I_C = 5 \text{ mA}, I_B = 0.25 \text{ mA}$	_	0.1	0.3	V
Input voltage (ON)	V _{I(ON)}	V _{CE} = 0.2 V, I _C = 5 mA	1.5	_	5.0	V
Input voltage (OFF)	V _{I(OFF)}	V _{CE} = 5 V, I _C = 0.1 mA	1.0	_	1.5	V
Transition frequency	f _T	V _{CE} = 10 V, I _C = 5 mA	_	250	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	3	_	pF
Input resistor	R1	_	32.9	47	61.1	kΩ
Resistor ratio	R1/R2	_	0.9	1.0	1.1	

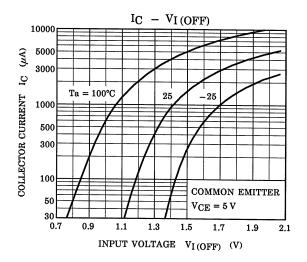
Q1

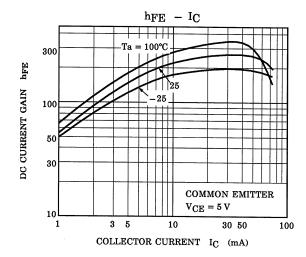


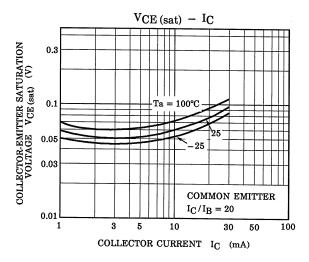
Q2

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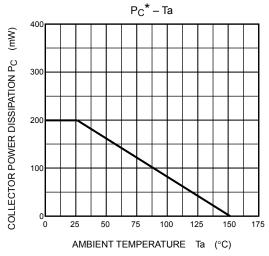






Q1, Q2 common

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*:Total rating

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20070701-EN GENERAL

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